



B3L30LP

3A SCHOTTKY BARRIER RECTIFIER

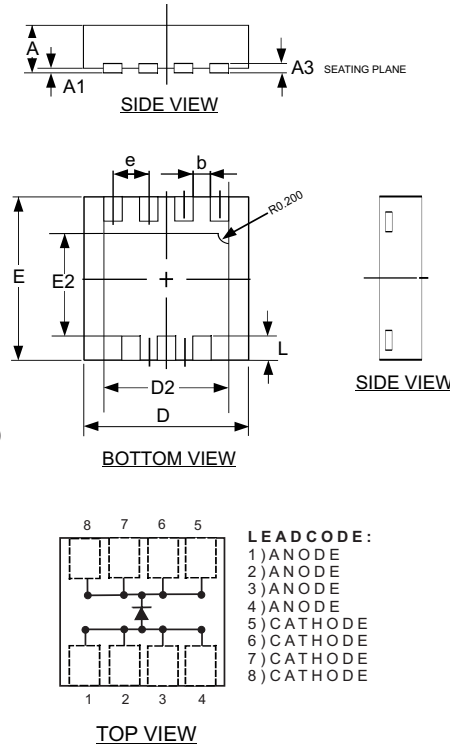
NEW PRODUCT

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- High Forward Surge Current Capability
- **Lead Free Finish, RoHS Compliant (Note 1)**
- "Green" Device (Note 3)

Mechanical Data

- Case: DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - NiPdAu annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 (e3)
- Polarity: See Diagram
- Marking: S33 (See Page 3)
- Weight: 0.0172 grams (approximate)



DFN3030-8			
Sym	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	—	—	0.15
b	0.29	0.39	0.34
D	2.90	3.10	3.00
D2	2.19	2.39	2.29
e	—	—	0.65
E	2.90	3.10	3.00
E2	1.64	1.84	1.74
L	0.30	0.60	0.45
All Dimensions in mm			

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	V
RMS Reverse Voltage	V _{R(RMS)}	21	V
Average Rectified Output Current	I _O	3.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I _{FSM}	30	A

Thermal Characteristics

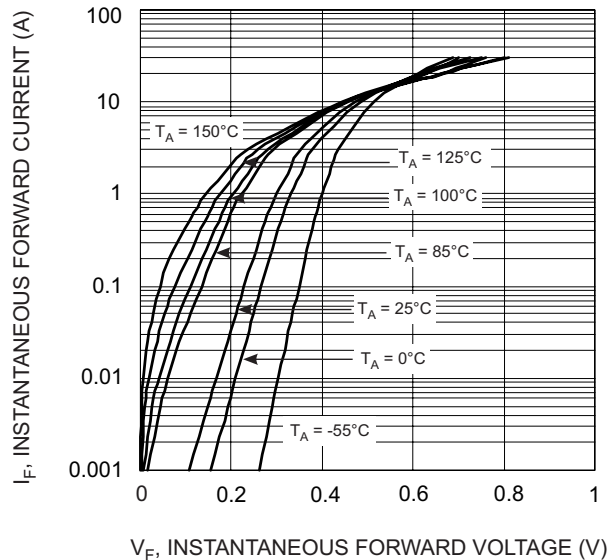
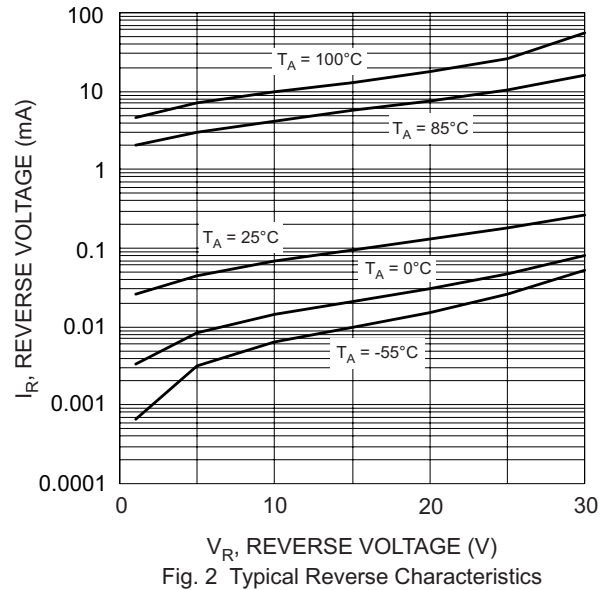
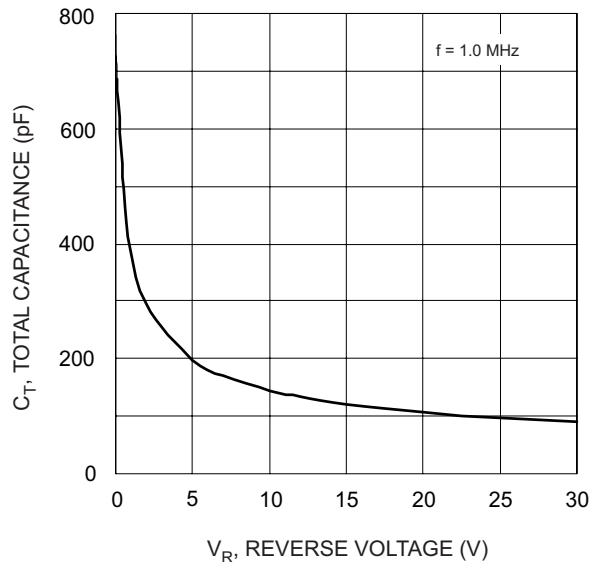
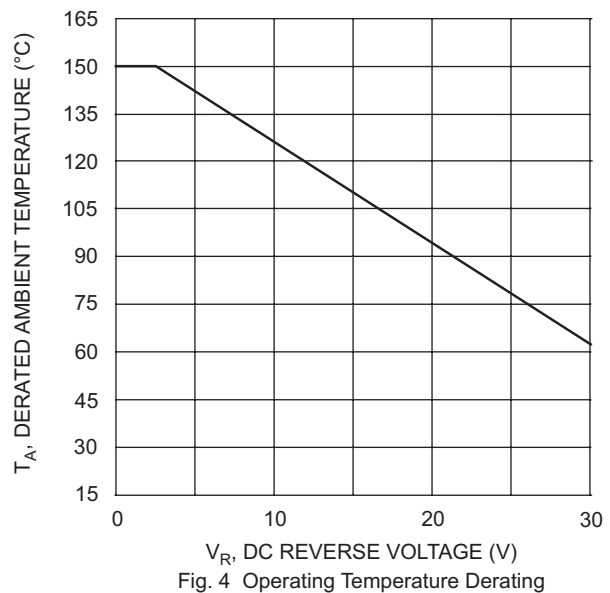
Characteristic	Symbol	Typ	Max	Unit
Thermal Resistance Junction to Soldering Point	R _{θJS}	—	3	°C/W
Thermal Resistance Junction to Ambient Air (Note 2)	R _{θJA}	130	—	°C/W
Power Dissipation (Note 2)	P _D	—	0.75	W
Operating Temperature Range	T _j	-65 to +150		
Storage Temperature Range	T _{STG}	-65 to +150		

Notes: 1. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see *EU Directive Annex Notes 5 and 7*.
2. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com/datasheets/ap02001.pdf>. T_A = 25°C.
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 4)	$V_{(BR)R}$	30	—	—	V	$I_R = 5.0\text{mA}$
Forward Voltage	V_F	—	0.30 0.18 0.33 0.22 0.35 0.26	0.35 0.29 0.40 0.37 0.45 0.42	V	$I_F = 1.0\text{A}, T_j = 25^\circ\text{C}$ $I_F = 1.0\text{A}, T_j = 125^\circ\text{C}$ $I_F = 2.0\text{A}, T_j = 25^\circ\text{C}$ $I_F = 2.0\text{A}, T_j = 125^\circ\text{C}$ $I_F = 3.0\text{A}, T_j = 25^\circ\text{C}$ $I_F = 3.0\text{A}, T_j = 125^\circ\text{C}$
Reverse Current (Note 4)	I_R	—	0.27 55	1.0 90	mA mA	$T_j = 25^\circ\text{C}, V_R = 30\text{V}$ $T_j = 100^\circ\text{C}, V_R = 30\text{V}$

Notes: 4. Short duration test pulse used to minimize self-heating effect.

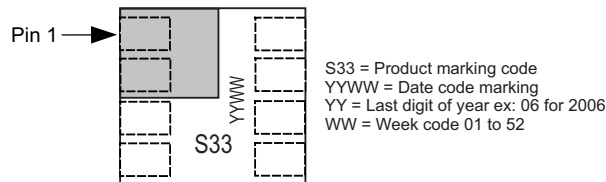


Ordering Information (Note 5)

Device	Packaging	Shipping
B3L30LP-7	DFN3030-8	3,000/Tape & Reel

Notes: 5. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



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